



## 74LCX16245

### Low-Voltage 16-Bit Bidirectional Transceiver with 5V Tolerant Inputs and Outputs

#### General Description

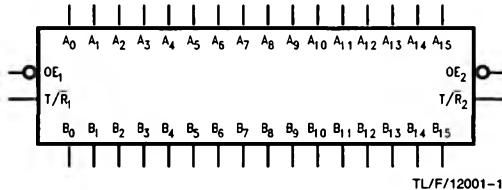
The 74LCX16245 contains sixteen non-inverting bidirectional buffers with TRI-STATE® outputs and is intended for bus oriented applications. The device is designed for low voltage (3.3V) V<sub>CC</sub> applications with capability of interfacing to a 5V signal environment. The device is byte controlled. Each byte has separate control inputs which could be shorted together for full 16-bit operation. The T/R inputs determine the direction of data flow through the device. The OE inputs disable both the A and B ports by placing them in a high impedance state.

The LCX16245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

#### Features

- 4.5 ns t<sub>PD</sub> max, 20 μA I<sub>CCQ</sub> max
- 5V tolerant inputs and outputs
- Power down high impedance inputs and outputs
- 2.0V–3.6V V<sub>CC</sub> supply operation
- ±24 mA output drive
- Implements patented Quiet Series™ noise/EMI reduction circuitry
- Functionally compatible with 74 series 16245
- Latch-up performance exceeds 500 mA
- ESD performance:  
Human body model > 2000V  
Machine model > 200V

#### Logic Symbol

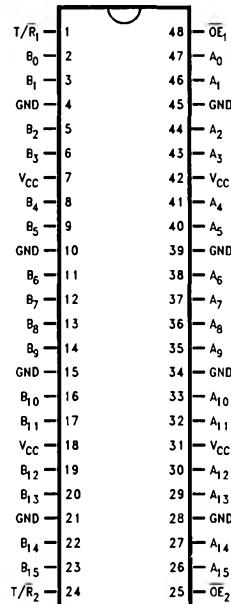


Pin Names	Description
OE	Output Enable Input
T/R	Transmit/Receive Input
A <sub>0</sub> -A <sub>15</sub>	Side A Inputs or TRI-STATE Outputs
B <sub>0</sub> -B <sub>15</sub>	Side B Inputs or TRI-STATE Outputs

	SSOP	TSSOP
Order Number	74LCX16245MEA 74LCX16245MEAX	74LCX16245MTD 74LCX16245MTDX
See NS Package Number	MS48A	MTD48

#### Connection Diagram

Pin Assignment for  
SSOP and TSSOP



TL/F/12001-2

**Truth Tables**

Inputs		Outputs
$\overline{OE}_1$	$T/\bar{R}_1$	
L	L	Bus $B_0-B_7$ Data to Bus $A_0-A_7$
L	H	Bus $A_0-A_7$ Data to Bus $B_0-B_7$
H	X	HIGH Z State on $A_0-A_7, B_0-B_7$

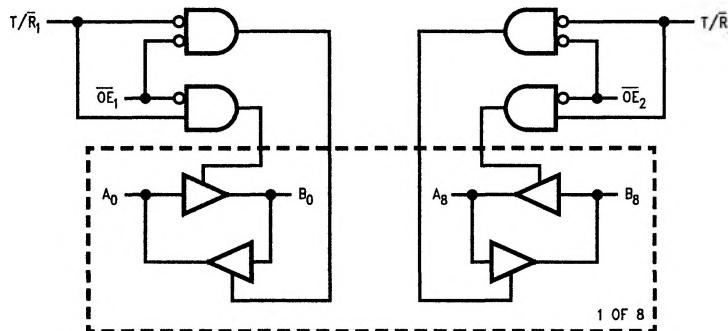
H = High Voltage Level

L = Low Voltage Level

X = Immaterial

Z = High Impedance

Inputs		Outputs
$\overline{OE}_2$	$T/\bar{R}_2$	
L	L	Bus $B_8-B_{15}$ Data to Bus $A_8-A_{15}$
L	H	Bus $A_8-A_{15}$ Data to Bus $B_8-B_{15}$
H	X	HIGH Z State on $A_8-A_{15}, B_8-B_{15}$

**Logic Diagram**

TL/F/12001-3

## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Symbol	Parameter	Value	Conditions	Units
V <sub>CC</sub>	Supply Voltage	−0.5 to +7.0		V
V <sub>I</sub>	DC Input Voltage	−0.5 to +7.0		V
V <sub>O</sub>	DC Output Voltage	−0.5 to +7.0	Output in TRI-STATE	V
		−0.5 to V <sub>CC</sub> + 0.5	Output in High or Low State (Note 2)	V
I <sub>IK</sub>	DC Input Diode Current	−50	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current	−50 +50	V <sub>O</sub> < GND V <sub>O</sub> > V <sub>CC</sub>	mA
I <sub>O</sub>	DC Output Source/Sink Current	±50		mA
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100		mA
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature	−65 to +150		°C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I<sub>O</sub> Absolute Maximum Rating must be observed.

## Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V <sub>CC</sub>	Supply Voltage	2.0	3.6	V
	Operating Data Retention	1.5	3.6	
V <sub>I</sub>	Input Voltage	0	3.6	V
V <sub>O</sub>	Output Voltage	0	V <sub>CC</sub> 5.5	V
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	V <sub>CC</sub> = 3.0V – 3.6V V <sub>CC</sub> = 2.7V	±24 ±12	mA
T <sub>A</sub>	Free-Air Operating Temperature	−40	85	°C
Δt/ΔV	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V	0	10	ns/V

## DC Electrical Characteristics

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = −40°C to +85°C		Units
				Min	Max	
V <sub>IH</sub>	HIGH Level Input Voltage		2.7–3.6	2.0		V
V <sub>IL</sub>	LOW Level Input Voltage		2.7–3.6		0.8	V
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = −100 μA	2.7–3.6	V <sub>CC</sub> – 0.2		V
		I <sub>OH</sub> = −12 mA	2.7	2.2		V
		I <sub>OH</sub> = −18 mA	3.0	2.4		V
		I <sub>OH</sub> = −24 mA	3.0	2.2		V
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.7–3.6		0.2	V
		I <sub>OL</sub> = 12 mA	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	V
		I <sub>OL</sub> = 24 mA	3.0		0.55	V
I <sub>I</sub>	Input Leakage Current	0 ≤ V <sub>I</sub> ≤ 5.5V	2.7–3.6		±5.0	μA
I <sub>OZ</sub>	TRI-STATE I/O Leakage	0 ≤ V <sub>O</sub> ≤ 5.5V V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.7–3.6		±5.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 5.5V	0		100	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>I</sub> = V <sub>CC</sub> or GND	2.7–3.6		20	μA
		3.6V ≤ V <sub>I</sub> , V <sub>O</sub> ≤ 5.5V	2.7–3.6		±20	μA
ΔI <sub>CC</sub>	Increase in I <sub>CC</sub> per Input	V <sub>IH</sub> = V <sub>CC</sub> – 0.6V	2.7–3.6		500	μA

## AC Electrical Characteristics

Symbol	Parameter	$T_A = -40^\circ\text{C to } +85^\circ\text{C}$				Units	
		$V_{CC} = 3.3V \pm 0.3V$		$V_{CC} = 2.7V$			
		Min	Max	Min	Max		
$t_{PHL}$	Propagation Delay $A_n$ to $B_n$ or $B_n$ to $A_n$	1.5	4.5	1.5	5.2	ns	
$t_{PLH}$		1.5	4.5	1.5	5.2	ns	
$t_{PZL}$	Output Enable Time	1.5	6.5	1.5	7.2	ns	
$t_{PZH}$		1.5	6.5	1.5	7.2	ns	
$t_{PLZ}$	Output Disable Time	1.5	6.4	1.5	6.9	ns	
$t_{PHZ}$		1.5	6.4	1.5	6.9	ns	
$t_{OSHL}$	Output to Output Skew (Note 1)		1.0			ns	
$t_{OSLH}$			1.0			ns	

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW ( $t_{OSHL}$ ) or LOW to HIGH ( $t_{OSLH}$ ). Parameter guaranteed by design.

## Dynamic Switching Characteristics

Symbol	Parameter	Conditions	$V_{CC}$ (V)	$T_A = 25^\circ\text{C}$	Units
				Typical	
$V_{OLP}$	Quiet Output Dynamic Peak $V_{OL}$	$C_L = 50 \text{ pF}, V_{IH} = 3.3V, V_{IL} = 0V$	3.3	0.8	V
$V_{OLV}$	Quiet Output Dynamic Valley $V_{OL}$	$C_L = 50 \text{ pF}, V_{IH} = 3.3V, V_{IL} = 0V$	3.3	0.8	V

## Capacitance

Symbol	Parameter	Conditions	Typical	Units
$C_{IN}$	Input Capacitance	$V_{CC} = \text{Open}, V_I = 0V \text{ or } V_{CC}$	7	pF
$C_{OUT}$	Output Capacitance	$V_{CC} = 3.3V, V_I = 0V \text{ or } V_{CC}$	8	pF
$C_{PD}$	Power Dissipation Capacitance	$V_{CC} = 3.3V, V_I = 0V \text{ or } V_{CC}, F = 10 \text{ MHz}$	20	pF

## 74LCX16245 Ordering Information

The device number is used to form part of a simplified purchasing code where the package type is defined as follows:

